Revision. 2

Transistors with Built-in Resistor

DRC2144V0L

# **Panasonic**

## DRC2144V0L

#### Silicon NPN epitaxial planar type

For digital circuits
Complementary to DRA2144V

#### ■ Features

- Low collector-emitter saturation voltage Vce(sat)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

■ Marking Symbol: NJ

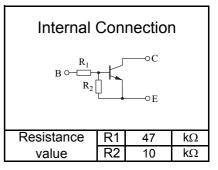
#### ■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

| Parameter                             | Symbol | Rating      | Unit |
|---------------------------------------|--------|-------------|------|
| Collector-base voltage (Emitter open) | VCBO   | 50          | V    |
| Collector-emitter voltage (Base open) | VCEO   | 50          | V    |
| Collector current                     | IC     | 100         | mA   |
| Total power dissipation               | PT     | 200         | mW   |
| Junction temperature                  | Tj     | 150         | °C   |
| Operating ambient temperature         | Topr   | -40 to +85  | °C   |
| Storage temperature                   | Tstg   | -55 to +150 | °C   |

## Unit: mm 2.9 0.4 0.16 3 (0. 95) (0. 95) 1.9 1. Base 2. Emitter 3. Collector Panasonic Mini3-G3-B JEITA SC-59A TO-236AA/SOT-23 Code



#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

| Parameter                                    | Symbol   | Conditions              | Min  | Тур | Max  | Unit |
|--|----------|-------------------------|------|-----|------|------|
| Collector-base voltage (Emitter open)        | VCBO     | IC = 10 μA, IE = 0      | 50   |     |      | V    |
| Collector-emitter voltage (Base open)        | VCEO     | IC = 2 mA, IB = 0       | 50   |     |      | V    |
| Collector-base cutoff current (Emitter open) | ICBO     | VCB = 50 V, IE = 0      |      |     | 0.1  | μΑ   |
| Collector-emitter cutoff current (Base open) | ICEO     | VCE = 50 V, IB = 0      |      |     | 0.5  | μΑ   |
| Emitter-base cutoff current (Collector open) | IEBO     | VEB = 6 V, IC = 0       |      |     | 0.2  | mA   |
| Forward current transfer ratio               | hFE      | VCE = 10 V, IC = 5 mA   | 30   |     |      | -    |
| Collector-emitter saturation voltage         | VCE(sat) | IC = 10 mA, IB = 0.5 mA |      |     | 0.25 | V    |
| Input voltage                                | Vi(on)   | VCE = 0.2 V, IC = 5 mA  | 6.3  |     |      | V    |
|  | Vi(off)  | VCE = 5 V, IC = 100 μA  |      |     | 1.9  | V    |
| Input resistance                             | R1       |                         | -30% | 47  | +30% | kΩ   |
| Resistance ratio                             | R1/R2    |                         | 3.7  | 4.7 | 5.7  | -    |

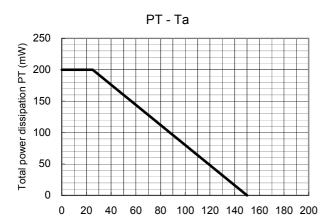
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

Established: 2009-10-30 Revised: 2014-03-07

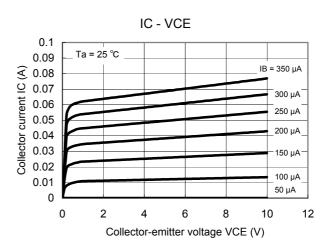
Transistors with Built-in Resistor **Panasonic** 

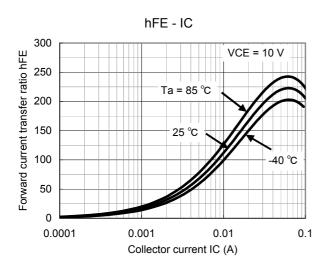
DRC2144V0L

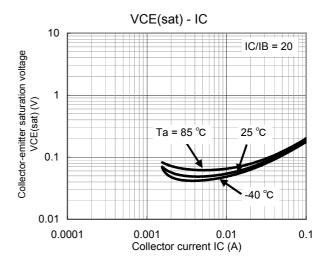
## Technical Data (reference)

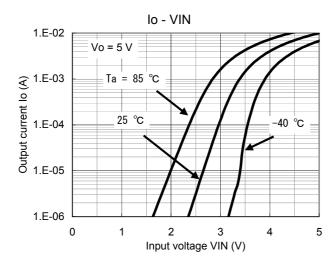


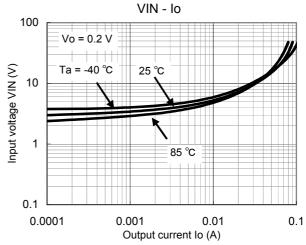
Ambient temperature Ta (°C)











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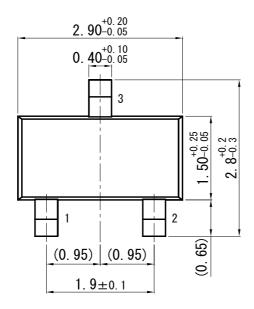
Transistors with Built-in Resistor

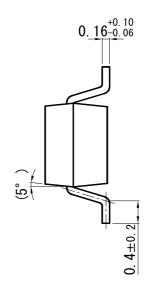
### DRC2144V0L

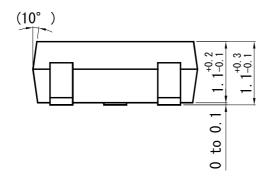
Mini3-G3-B

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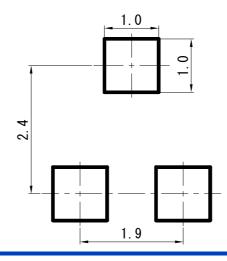
Unit: mm







■ Land Pattern (Reference) (Unit: mm)



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